

## GENERAL PURPOSE PHOTO REFLECTOR

### ■ GENERAL DESCRIPTION

The NJL5194K is miniature and thin general purpose photo reflector, which can be soldering by reflow-method.

This device attains high durability after reflow same as NJL5181K/83K, and consists of high output infrared emitting and high sensitive Si photo darlington transistor, and attains high cost performance.

In order to prevent from degradation of this device in moisturing at reflow method, so that keep the precaution for handling.

### ■ FEATURES

- Miniature, thin type
- Built-in visible light cut-off filter
- High output, high S/N ratio

### ■ APPLICATIONS

- End detector of video, audio tape
- Rotation detection and control of various motors, audio turntables
- Paper edge detection and mechanism timing detection of facsimile, printer, X-Y recorder
- Reading film information and mechanism timing detection of camera
- Reading out the characters of bar code reader, encoder and automatic vending machine
- Various detection of industrial system, such as FDD, Robot

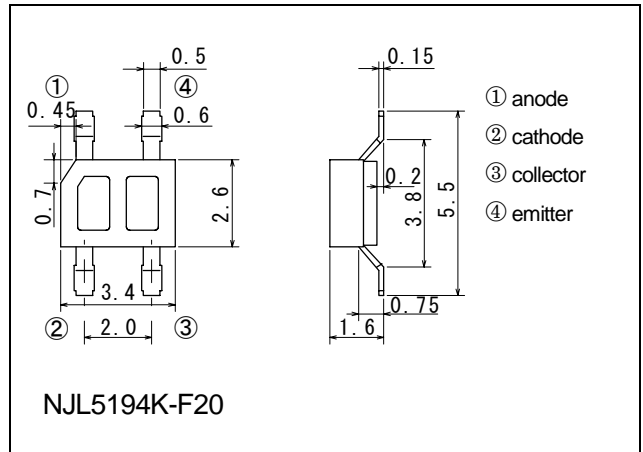
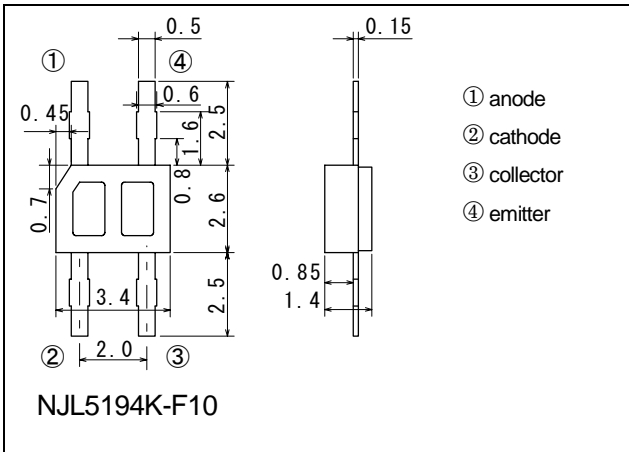
### ■ ABSOLUTE MAXIMUM RATINGS (Ta=25°C)

PARAMETER	SYMBOL	RATINGS	UNIT
<b>Emitter</b>			
Forward Current (Continuous)	IF	30	mA
Reverse Voltage (Continuous)	VR	6	V
Power Dissipation	PD	45	mW
<b>Detector</b>			
Collector-Emitter Voltage	VCEO	16	V
Emitter-Collector Voltage	VECO	6	V
Collector Current	IC	20	mA
Collector Power Dissipation	PC	50	mW
<b>Coupled</b>			
Total Power Dissipation	Ptot	80	mW
Operating Temperature	Topr	-20 to +85	°C
Storage Temperature	Tstg	-40 to +85	°C
Reflow Soldering Temperature	Tsol	260(10sec. 1.5mm from body)	°C

### ■ ELECTRO-OPTICAL CHARACTERISTICS (Ta=25°C)

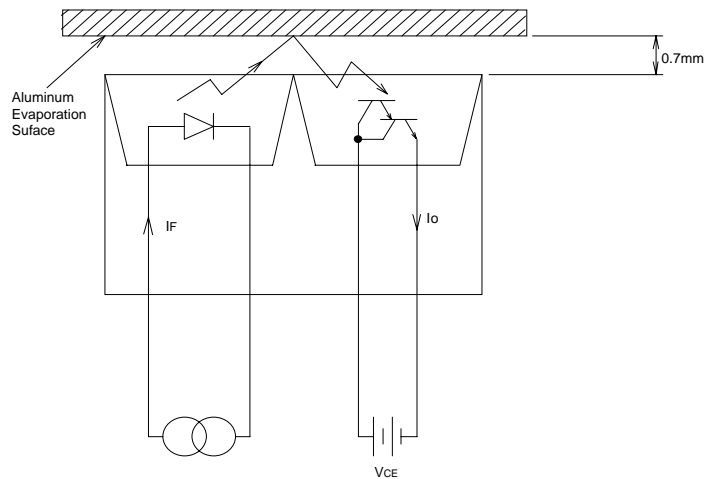
PARAMETER	SYMBOL	TEST CONDITION	MIN	TYP	TYP	UNIT
<b>Emitter</b>						
Forward Voltage	VF	IF=4mA	—	—	1.4	V
Reverse Current	IR	VR=6V	—	—	10	μA
Capacitance	Ct	VR=0V, f=1MHz	—	25	—	pF
<b>Detector</b>						
Dark Current	ICEO	VCE=10V	—	—	1	μA
Collector-Emitter Voltage	VCEO	IC=100μA	16	—	—	V
<b>Coupled</b>						
Output Current	IO	IF=4mA, VCE=2V, d=0.7mm	1.9	—	7.4	mA
Operating Dark Current	ICEOD	IF=4mA, VCE=2V	—	—	1	μA
Rise Time	tr	IO=100μA, VCE=2V, RL=1KΩ, d=0.7mm	—	100	—	μs
Fall Time	tf	IO=100μA, VCE=2V, RL=1KΩ, d=0.7mm	—	70	—	μs

## ■ OUTLINE (typ.) UNIT:mm

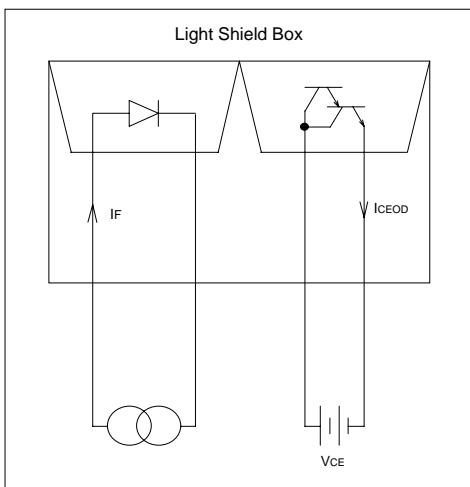


## ■ MEASURING SPECIFICATION FOR OUTPUT CURRENT

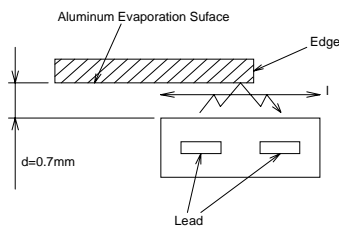
The output current can be measured  
When reflected at the aluminum



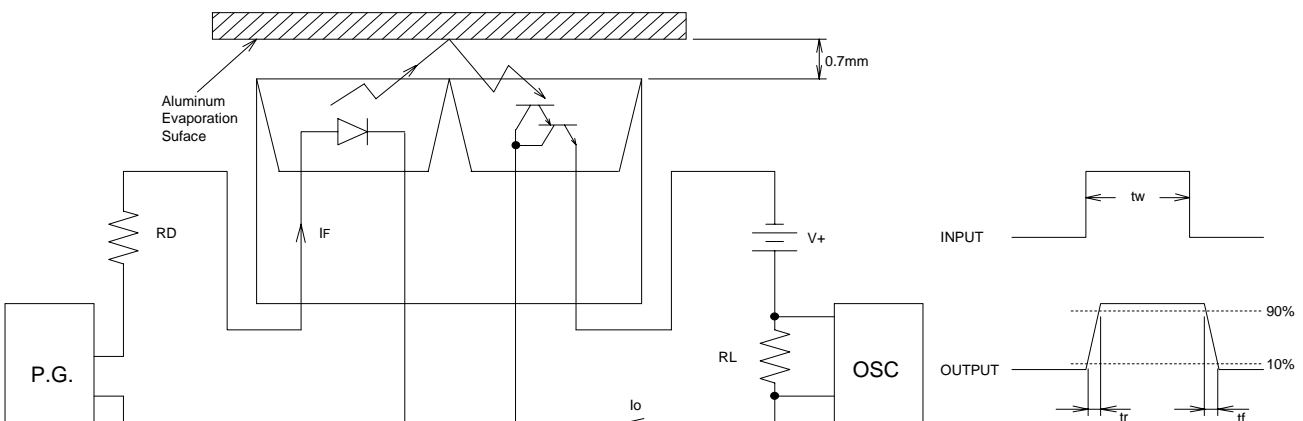
## ■ MEASURING CIRCUIT FOR OPERATING DARK CURRENT



## ■ MEASURING SPECIFICATION FOR EDGE RESPONSE

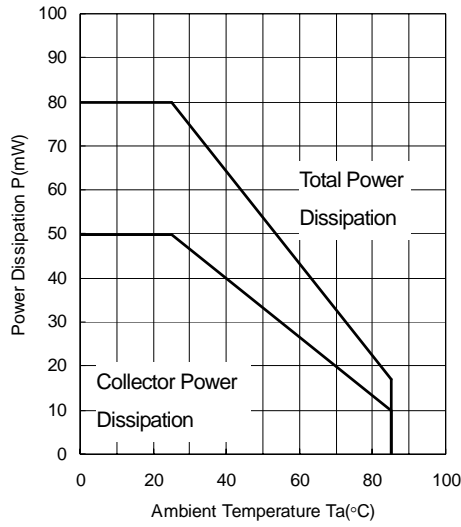


## ■ MEASURING CIRCUIT FOR RESPONSE TIME

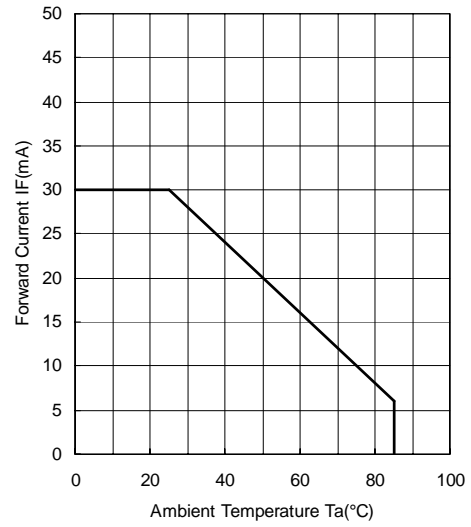


## MAXIMUM RATING CURVES

Power Dissipation vs. Temperature

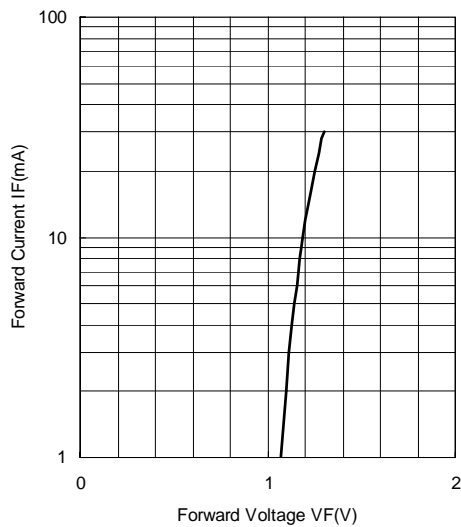


Forward Current vs. Temperature

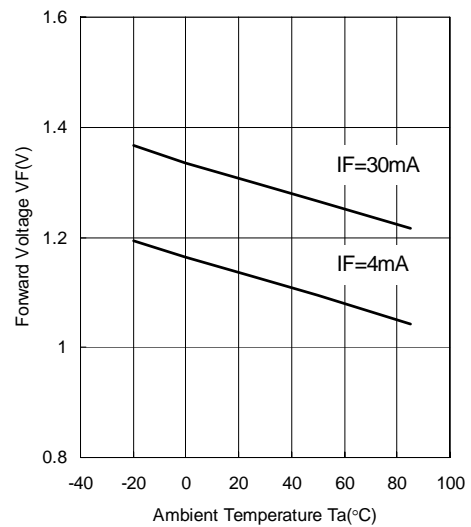


## TYPICAL CHARACTERISTICS

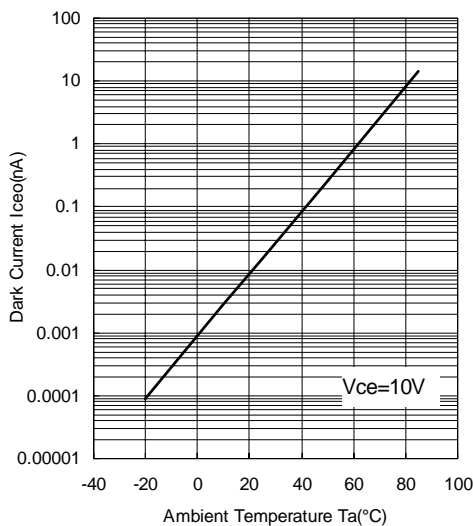
Forward Voltage vs. Forward Current



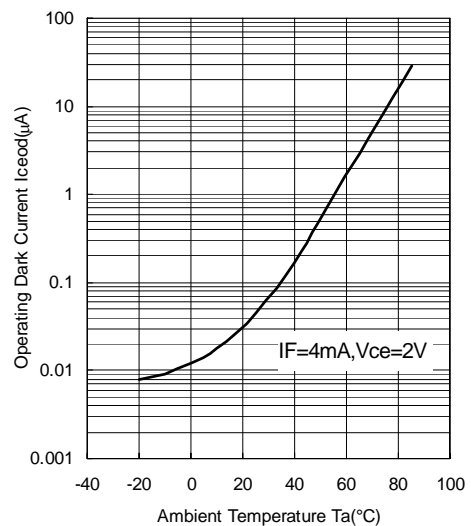
Forward Voltage vs. Temperature



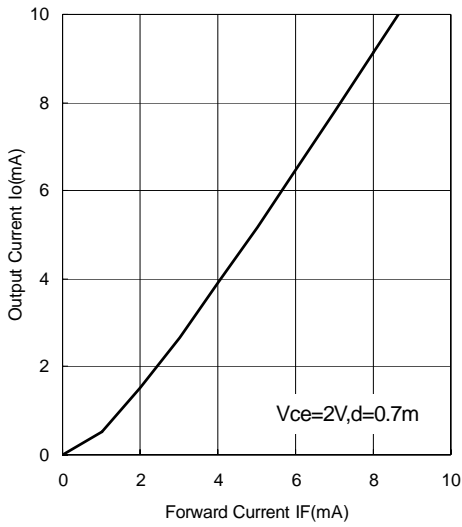
Dark Current vs. Temperature



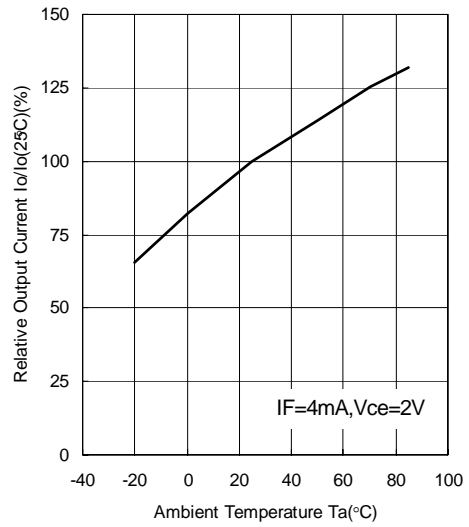
Operating Dark Current vs. Temperature



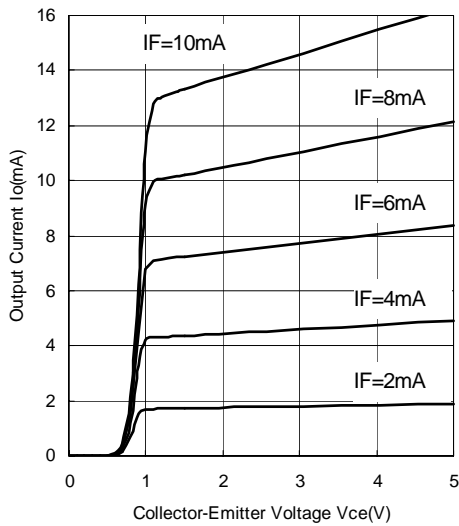
**Output Current vs. Forward Current**  
( $T_a=25^\circ\text{C}$ )



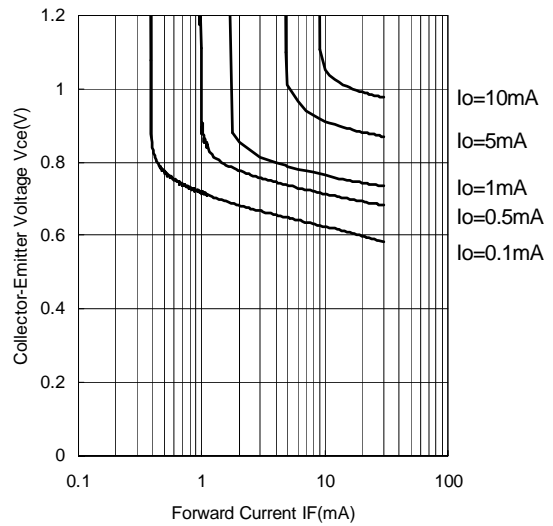
**Output Current vs. Temperature**



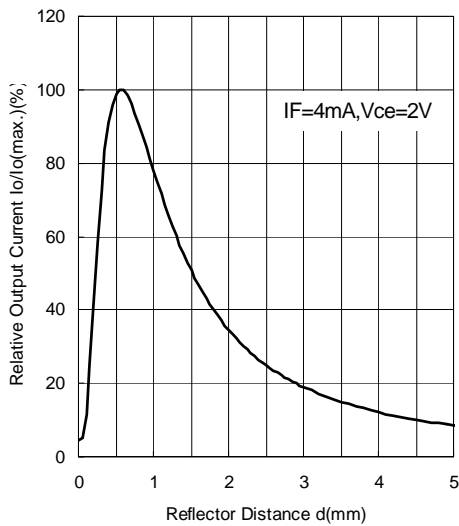
**Output Characteristics** ( $T_a=25^\circ\text{C}$ )



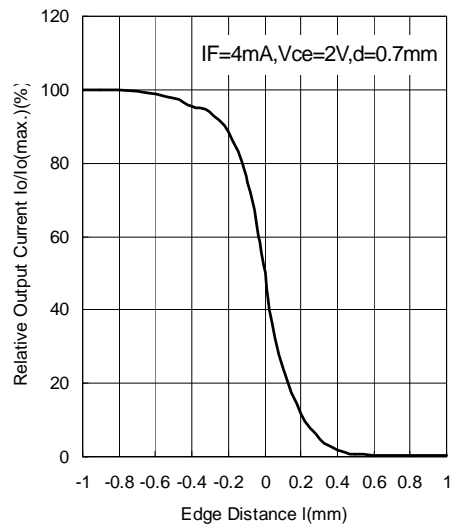
**V\_{ce} Saturation** ( $T_a=25^\circ\text{C}$ )



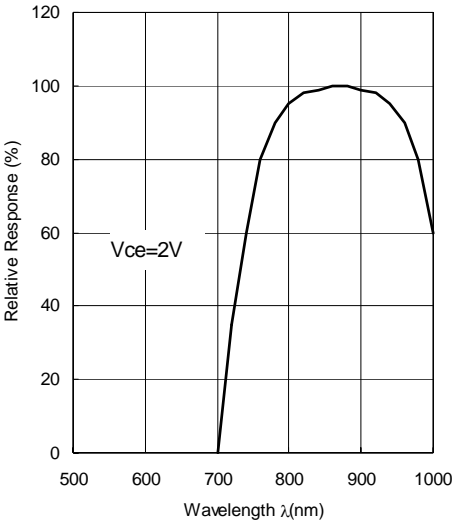
**Output Current vs. Distance** ( $T_a=25^\circ\text{C}$ )



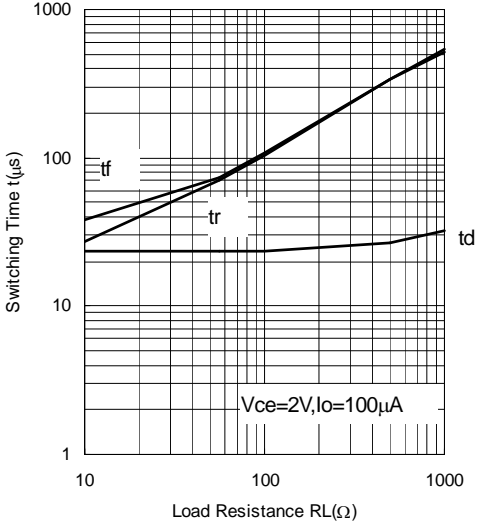
**Output Current vs. Edge Distance** ( $T_a=25^\circ\text{C}$ )



Spectral Response (Ta=25°C)



Switching Time vs. Load Resistance (Ta=25°C)



## PRECAUTION FOR HANDLING

### 1. Soldering to actual circuit board

#### Soldering condition

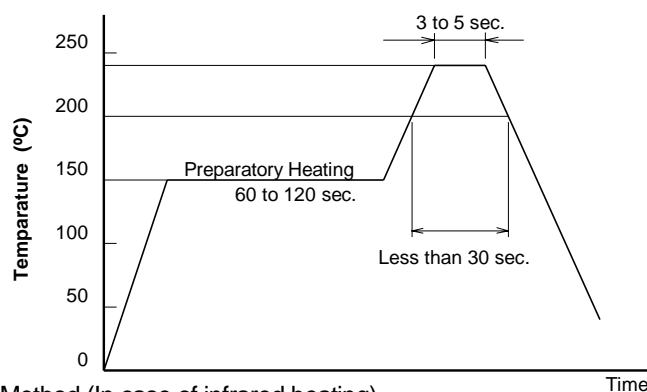
- Lead's of soldering temperature and heating time.  
260°C maximum, less than 10 seconds, at least 1.5mm from body.
- Heated condition of plastic package.  
Lower then 240°C of maximum surface temperature, less than 30 seconds of time kept higher then 200°C.

#### Soldering Method

##### 1) Reflow Method

Recommended temperature profile of its method.

- ① Preparatory heating condition : 120 to 150°C about 60 sec.
- ② Recommended soldering temperature : 230 to 240°C about 3 to 5 sec.
- ③ Slowly cool down right after soldering.
- ④ Soldering to be done within twice under this condition.



##### 2) Reflow Method (In case of infrared heating)

- Temperature Profile : Same to the above
- Avoid direct irradiation to the plastic package because it is black colored, absorbs the Infrared Radiation and its surface temperature will be higher than lead itself.

##### 3) The other method

Avoid rapid heating up like dipping the devices directly into the melting solder or vapor phase method (VPS).

If the device is heated to high temperature and kept in its condition for longer time, it would affect to its reliability. It is necessary to solder in short time as soon as possible.

### 2. Cleaning

Avoid washing the device after soldering by reflow method.

### 3. Attention in handling

- 1) Treat not to touch the lens surface.
- 2) Avoid dust and any other foreign materials (paint, bonding materials) on the lens surface.
- 3) Never to apply reverse voltage ( $V_{EC}$ ) of more then 6V on the photo transistor when measuring the characteristics or adjusting the system. If applied, it causes to lower the sensitivity.
- 4) When mounting, special care has to be taken on the mounting position and tilting on the device because it is very important to place the device to the optimum position to the object.

### 4. Storage

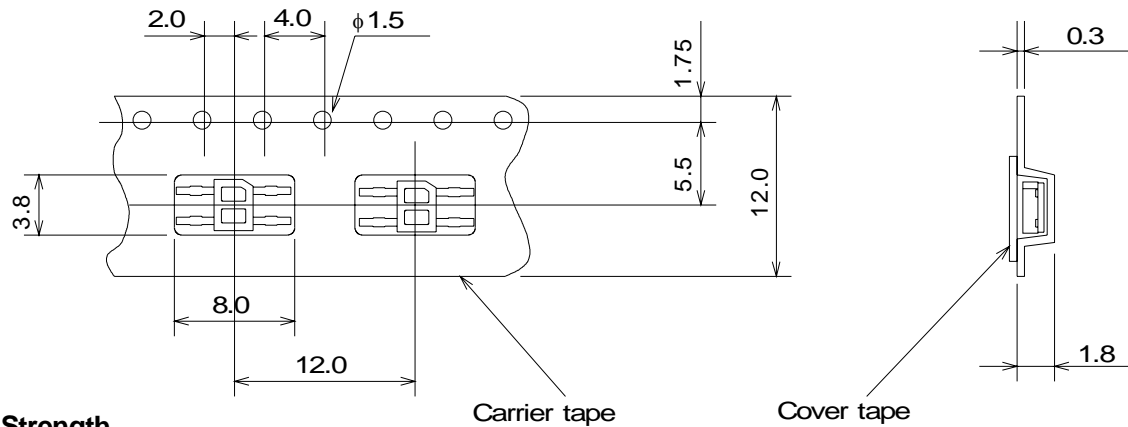
In order to prevent from degradation of this device in moisturing at reflow method, so that this device is contained in deaeration packing. And the leads are silver plated and they are discolored if the device is left open to the air for long after taken out of the envelope. It causes deterioration of soldering characteristics. So that mount the device as short as possible after opening the envelope.

## NJL5194K-F10 Taping Specification

(TE1)

### 1. Taping size

- 1) Carrier tape is used with Styrene type Carbonated Plastic.
- 2) Cover tape is used with electro statistically prevention treated Polyester type tape.
- 3) Product taping direction is to place the index mark against the pull out direction of the tape as in the drawing.

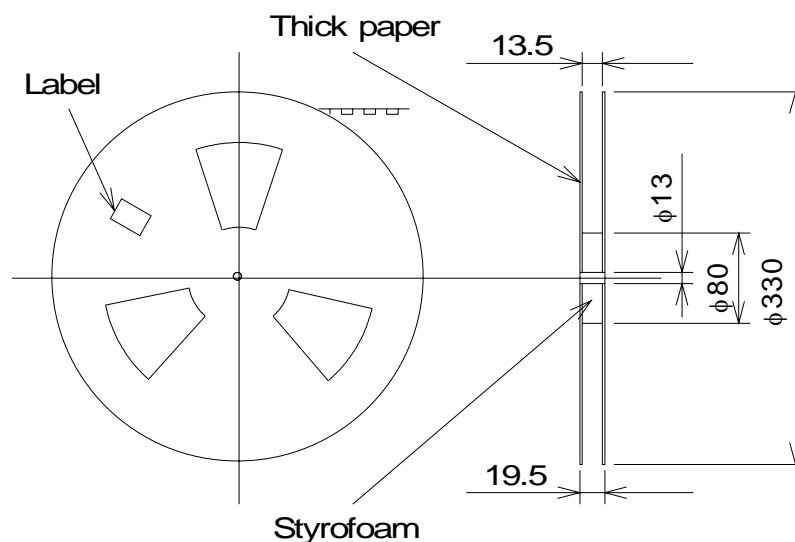


### 2. Taping Strength

Pullup the cover tape from the carrier tape, and when the opening angle comes around 10 to 15 ° , and the peeling-off strength is to be within the power of 20 to 70g.

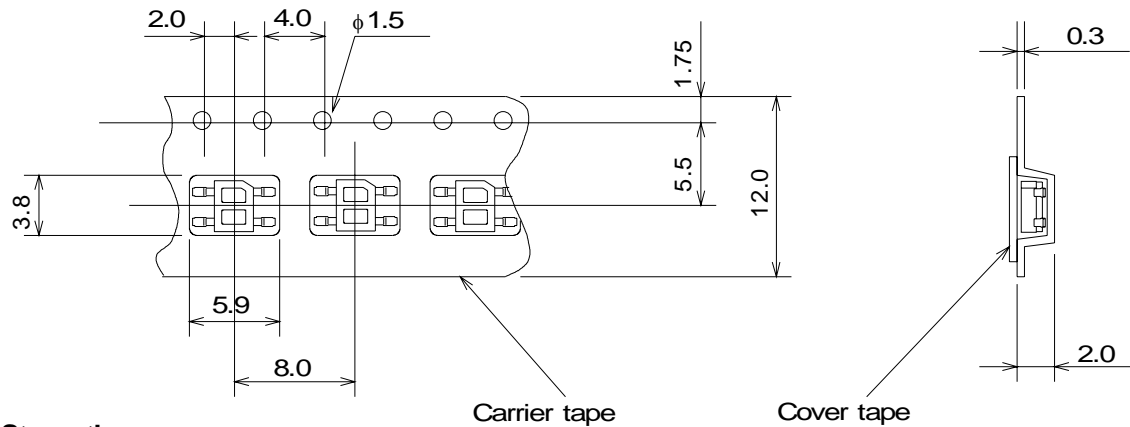
### 3. Packaging

- 1) The taped products are to be rolled up on the taping reel as on the drawing
- 2) Rolling up specification
  - ① Start rolling : Carrier tape open space more than 20 Peaces.
  - ② End of rolling : Carrier tape open space more than 20 Peaces, and 2 round of reel space at the cover tape only.
- 3) Taping quantity : 3,000 Pieces
- 4) Seal off after putting each reels in a vinyl bag with silica gel (3 bags).



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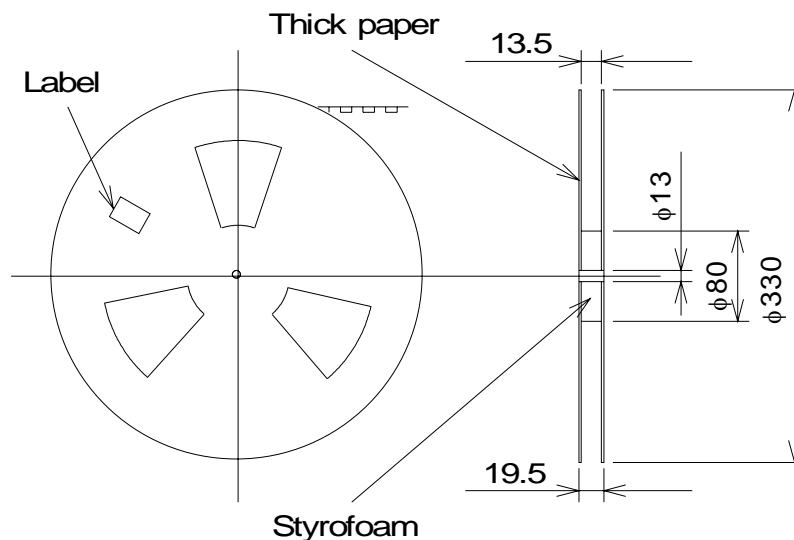


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  - ① Start rolling : Carrier tape open space more than 20 Peaces.
  - ② End of rolling : Carrier tape open space more than 20 Peaces, and 2 round of reel space at the cover tape only.
- 3) Taping quantity : 4,000 Pieces
- 4) Seal off after putting each reels in a vinyl bag with silica gel (3 bags).



**[CAUTION]**

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